# NSN 5962-01-516-5910

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## **Body Length:**

Between 0.540 inches and 0.560 inches

## Body Width:

Between 0.060 inches and 0.120 inches

## **Body Height:**

Between 0.442 inches and 0.458 inches

## **Maximum Power Dissipation Rating:**

1.0 watts

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Burn in, mil-std-883, class b and low power and electrostatic sensitive

### Inclosure Configuration:

Leadless flat pack

## **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

## Case Outline Source And Designator:

C12 mil-m-38510

## **Current Rating Per Characteristic:**

110.00 milliamperes reverse current, dc absolute

## **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

-0.5 volts total supply and 7.0 volts total supply

### **Time Rating Per Chacteristic:**

25.00 nanoseconds access

### Memory Device Type:

Ram

# Memory Capacity:

8k x 8

## **Special Features:**

Data retention

# Terminal Type And Quantity:

28 leadless

# Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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